

# **1N4001G - 1N4007G**

**1.0 AMP Glass Passivated Rectifiers**

**DO-41**

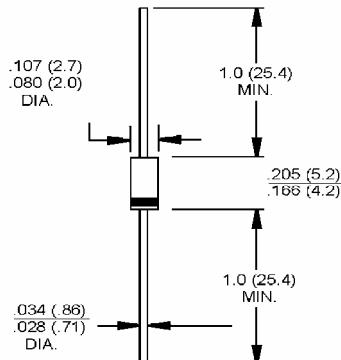


## **Features**

- ◊ Glass passivated chip junction
- ◊ High current capability, Low VF.
- ◊ High reliability & Current capability.
- ◊ High surge current capability.
- ◊ Low power loss, high efficiency.
- ◊ Green compound with suffix "G" on packing code & prefix "G" on datecode.

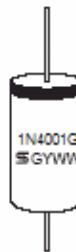
## **Mechanical Data**

- ◊ Cases: Molded plastic DO-41
- ◊ Epoxy: UL 94V-O rate flame retardant
- ◊ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ◊ Polarity: Color band denotes cathode.
- ◊ High temperature soldering guaranteed: 260oC/10 seconds/.375",(9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ◊ Weight: 0.34 gram



## **Dimensions in inches and (millimeters)**

### **Marking Diagram**



1N4001G = Specific Device Code  
 G = Green Compound  
 Y = Year  
 WW = Work Week

## **Maximum Ratings and Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified.

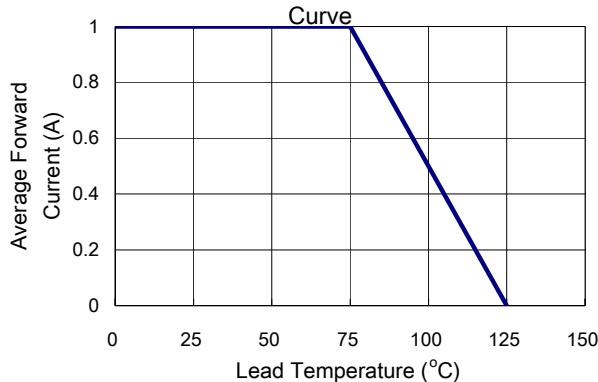
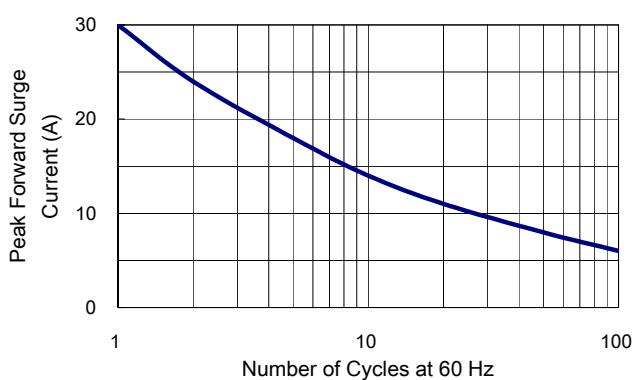
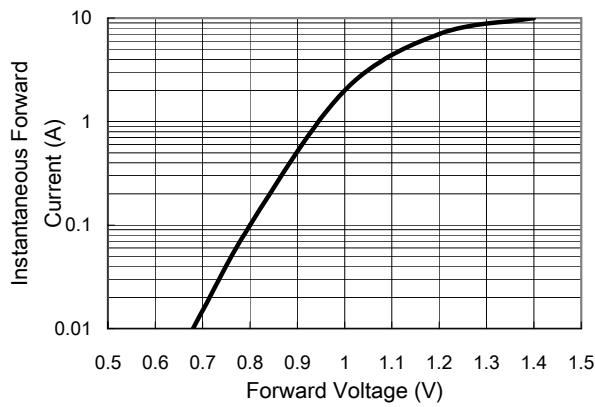
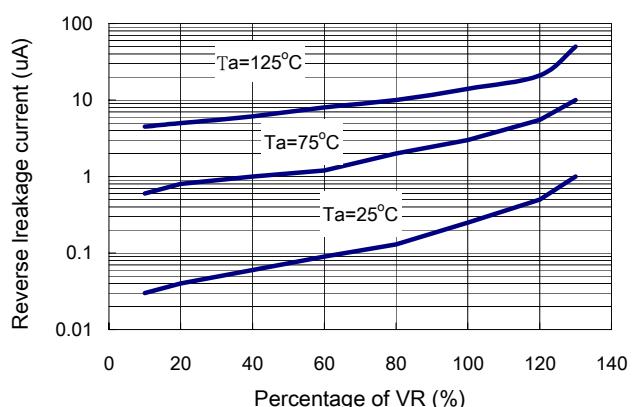
Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	1N 4001G	1N 4002G	1N 4003G	1N 4004G	1N 4005G	1N 4006G	1N 4007G	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ T <sub>A</sub> = 75°C	I <sub>(AV)</sub>						1.0		A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )	I <sub>FSM</sub>						30		A
Maximum Instantaneous Forward Voltage @ 1.0A	V <sub>F</sub>						1.0		V
Maximum DC Reverse Current @ T <sub>A</sub> =25°C at Rated DC Blocking Voltage @ TA=125°C	I <sub>R</sub>					5.0			uA
Typical Junction Capacitance (Note 2)	C <sub>j</sub>					10			pF
Typical Thermal Resistance (Note 1)	R <sub>θJA</sub>					80			°C/W
Operating Temperature Range	T <sub>J</sub>				-65 to +150				°C
Storage Temperature Range	T <sub>STG</sub>				-65 to +150				°C

Notes: 1. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

**RATINGS AND CHARACTERISTIC CURVES (1N4001G THRU 1N4007G)**
**FIG.1 Maximum Forward Current Derating Curve**

**FIG 2 Maximum Forward Surge Current**

**FIG 3 Typical Forward Characteristics**

**FIG 4 Typical Reverse Characteristics**

**FIG 5 Typical Junction Capacitance**
